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ECLinPS Lite™ MC100LVELT22 SPICE Model Kit

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Introduction

The objective of this kit is to provide schematic and SPICE parameter information for performing system level interconnect modeling with the Low Voltage ECLinPS Lite Translator TTL to PECL "LVELT22" device. The LVELT22 device is a dual 1 Bit translator from LVTTL/LVCMOS levels to PECL levels. This kit contains model netlists and



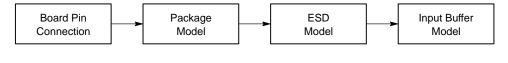
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APPLICATION NOTE

transistor parameter descriptions for the Input and Output buffers, package models, and ESD protection networks for Input and Output circuits used by the LVELT22 device. These may be interconnected as subcircuits to simulate buffer signals.

Subcircuit Interconnects for Input Pins



Subcircuit Interconnects for Output Pins

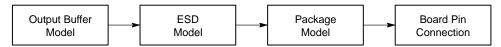


Figure 1. Input and Output Models

Input and Output Buffers

The LVTTL–LVPECL Translator subcircuits use SPICE level 3 netlists in circuit buffer models LVTTLIN and LVTTLOUT. All inputs and outputs are protected by ESD "Electro Static Discharge" protection circuitry. If the user would like to just simulate the output behavior, LVTTLOUT circuit can be stimulated with internal signals levels:

Voltage Internal Input Low	VIIL	VCC-1.1
Voltage Internal Input High	VIIH	VCC-0.8

Package

The MC100LVELT22 is only packaged in the 8 pin SOIC case outline. The coupled transmission line package model, LINES, may to be added to all external pins. In this subcircuit model, all external board side connections of input, output, and supply pins are called N**O and all internal chip side connections of input, output, and supply pins are referred to as N**I as shown in Table 1.

Table 1.

8 Pin SOIC Package Model				
Pin Connection	Outside to Board	Internal to Chip		
1	N01O	N01I		
2	N02O	N02I		
3	N03O	N03I		
4	N04O	N04I		
5	N05O	N05I		
6	N06O	N06I		
7	N07O	N07I		
8	N08O	N08I		

The LINES model considers the capacitance to be lumped. Minimum (fastest) useable edge rate is 0.076 NS.

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Modeling

The bias driver schematics for VCS and V1 generation are not included in this kit, as they are unnecessary for interconnection simulation. In addition their detailed netlist modeling would result in a relatively large increase in simulation time. Alternatively the internal reference voltages should be driven with ideal constant voltage sources. This model kit is intended for simulations within the specified power supply range. If supply voltages drop below minimum specification, VCS and V1 can no longer be assumed to be constant. Thus, this model kit should not be used for power up or power down simulations. LVPECL outputs should be terminated properly, such as through ohms to VTT=VCC-2V.

The common global nodes are as follows:

```
*100 VCC
*200 VEE
*300 VCS internal TTL reference = VEE+1.3V
*400 V1 internal TTL reference = 1.5
*10 IN
*5 QI VCC-1.1 TO VCC-0.8
*6
   QIB VCC-0.8 TO VCC-1.1
*20 D
*21 DB
*60 Q
*62 QB
*1 to external PIN
*2 to internal chip CKT
*3 external PIN and internal chip CKT node
*LVTTLIN
.SUBCKT LVTTLIN 100 200 300 400 10 5 6
        10
                 200
                      TN6
01 1
             3
        400 3
Q2 2
                 200
                      TN6
Q3 100 1
             6
                 200
                      TN6
Q4 100 2
             5
                 200
                      TN6
        300 7
Q5 3
                 200
                      TN6
Q6
   6
        300
            8
                 200
                      TN6
07
   5
        300 9
                 200
                      TN6
R1 100 1
             266
* TC=0.26M, 0.9U
R2 100 1
             266
* TC=0.26M, 0.9U
        200 42
R3 7
* TC=0.26M, 0.9U
R4 8
       200 42
* TC=0.26M, 0.9U
   9 200 42
R5
* TC=0.26M, 0.9U
.ENDS LVTTLIN
.SUBCKT LVTTLOUT 100 200 300 20 21 60 62
Q1
    62
         20 1 200 TRANA
Q2
    60
         21 1
                200 TRANA
03
    1
         300 2
                200 TRANA
    100 60 269
R1
* TC=0.26M, 0.9U
R2
    100 62 269
* TC=0.26M, 0.9U
R3
    2
         200 112
* TC=0.26M, 0.9U
.ENDS LVTTLOUT
```

ESD

The ESD protection for the inputs pins D0 and D1 uses the subcircuit model ESDIN. In the ESDIN model, a diode (CBVCC) goes to V_{CC} with a parallel resistor of high value (75 k Ω) and a diode pair (CBSUB devices) go to V_{EE} . The input has a series resistor. . SUBCKT ESDIN 100 200 1 2

D1 1 100 CBVCC D2 1 200 CBSUB

D3 1 200 CBSUB R1 1 VCC 75K * TC=0.26M, 0.9U R2 1 2 93 .END ESDIN The ESD model for the PECL output pins (Q0, Q0bar, Q1, Q1bar) use subcircuit model ESDOUT. The ESDOUT is modeled as diode (CBVCC) to V_{CC} and a diode pair (CBSUB devices) to V_{EE}. .SUBCKT ESDOUT 100 200 1 D1 1 100 CBVCC D2 1 200 CBSUB D3 1 200 CBSUB . END ESDOUT .MODEL CBVCC D + (IS = 1.00E15 CJO = 527fF Vj = 0.545 M = 0.32 BV = 14.5 + IBV = 0.1E6 XTI = 5 TT = 1nS) .MODEL CBSUB D + (IS = 1.00E15 CJO = 453fF TT = 1nS) NPN .MODEL TN6 +(IS = 8.56E-18 BF = 120 NF = 1VAF = 30IKF = 10.5mAVAR = 5 + ISE = 4.48E-16 BR = 10 NE = 2IKR = 922uA+ IRB = 13.2uA RB = 291.4 RBM = 95.0 RE = 13.3 RC = 62.7 VJE = .9MJE = .4+ CJE = 29.9 fFXTB = 0.73+ CJC = 31.2fFVJC = .67MJC = .32 XCJC= .3 FC = .9 + CJS = 60.9 fFVJS = .6MJS = .4XTF = 10VTF = 1.4V ITF = 27.6mA + TF = 8pS TR = 1nS+ ISC=0 EG=1.11 XTI=5.2 PTF=0 KF=0 AF=1 NR = 1NC=2) .MODEL TRANA NPN +(IS = 2.09E - 17 BF = 120)NF = 1VAF = 30IKF = 25.7mA+ ISE = 1.09E-15 BR = 10 NE = 2 VAR = 5 IKR = 2.25mA + IRB = 32.2uA RB = 122.6 RBM = 42.2 RE = 5.44 RC = 32.8 + CJE = 67.4fFVJE = .9MJE = .4 XTB = 0.73 + CJC = 53.8fF VJC = .67 MJC = .32 XCJC= .3 + CJS = 103 fFVJS = .6MJS = .4 FC = .9 + TF = 8pS TR = 1nSXTF = 10 VTF = 1.4V ITF = 67.5mA + ISC=0 EG=1.11 XTI=5.2 PTF=0 KF=0 AF=1 NR=1 NC=2) 1.75 x 13.50 emitter (2 emitters) PACKAGE MODEL TRANSMISSION LINES * CONNECT CHIP SIDE TO N**I AND BOARD SIDE TO N**O .SUBCKT LINES NO1I NO1O NO2I NO2O NO3I NO3O NO4I NO4O + N05I N050 N06I N060 N07I N070 N08I N080 N01M LO1WB NOli 1.367E-09 N010 L01 N01M 7.794E-10 C01 N01M 0 2.445E-13 1.287E-09 L02WB N02I N02M N02M N02O T-02 5.473E-10 N02M 0 C02 1.888E-13 LO3WB NO3I NO3M 1.287E-09 L03 N03M N030 5.473E-10 C03 N03M 0 1.901E-13 L04WB N04I N04M 1.367E-09 L04 N04M N04O 7.723E-10 N04M 2.443E-13 C04 0 L05WB N05I N05M 1.367E-09 L05 N05M N050 7.710E-10 C05 N05M 0 2.478E-13 LOGWB NOGI NOGM 1.287E-09 N06M N060 T-06 5.489E-10 C06 NOGM 0 1.916E-13

L07WB	N07I	N07M	1.287E-09	
L07	N07M	N070	5.495E-10	
C07	N07M	0	1.930E-13	
L08WB	N08I	N08M	1.367E-09	
L08	N08M	N080	7.786E-10	
C08	N08M	0	2.451E-13	
K0102	L01	L02	0.1687	
K0102WB	L01WB	L02WB	0.3400	
C0102	N010	N020	3.674E-14	
K0103	L01	L03	0.0702	
K0103WB	L01WB	L03WB	0.1847	
K0203	L02	L03	0.1822	
K0203WB	L02WB	L03WB	0.3505	
C0203	N020	N030	3.521E-14	
K0204	L02	L04	0.0682	
K0204WB	L02WB	L04WB	0.1847	
К0304	L03	L04	0.1694	
K0304WB	L03WB	L04WB	0.3400	
C0304	N030	N040	3.675E-14	
K0305WB	L03WB	L05WB	0.1847	
K0405WB	L04WB	L05WB	0.3455	
K0406WB	L04WB	LOGWB	0.1847	
K0506	L05	L06	0.1697	
K0506WB	L05WB	LOGWB	0.3400	
C0506	N050	N060	3.720E-14	
K0507	L05	L07	0.0682	
K0507WB	L05WB	L07WB	0.1847	
K0607	L06	L07	0.1824	
K0607WB	L06WB	L07WB	0.3505	
C0607	N060	N070	3.570E-14	
K0608	L06	L08	0.0702	
K0608WB	LOGWB	L08WB	0.1847	
K0708	L07	L08	0.1691	
K0708WB	L07WB	L08WB	0.3400	
C0708	N070	N080	3.632E-14	
.ENDS LINES				

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